



#4/Election/Amdt
A
11-23-03
PATENT Moore

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of:)

Jen-Inn Chyi)

Application No: 10/039,199)

Filed: January 4, 2002)

For: BUFFER LAYER OF LIGHT)
EMITTING SEMICONDUCTOR DEVICE)
AND METHOD OF FABRICATING THE)
SAME)

Examiner: Louie, Wai Sing

Group Art Unit: 2814

Date: January 13, 2003

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CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, Washington, DC 20231 on January 13, 2003.

Signed: _____

Kay Harlow

RESPONSE TO RESTRICTION REQUIREMENT AND AMENDMENT

Commissioner for Patents
Washington, DC 20231

Dear Sir:

In response to the Restriction Requirement dated December 11, 2002, Applicant hereby elects, without traverse, group II, claims 11-20 and 21-23 to prosecute in the above-identified patent application.

IN THE CLAIMS

Please amend the claims as follows:

Please cancel claims 1-10 and 24-32, without prejudice.

14. (Amended) The method as claimed in claim 13, wherein said metallic nitride layer is an InN layer.

15. (Amended) The method as claimed in claim 11, wherein said metal layer is an aluminum layer.

16. (Amended) The method as claimed in claim 15, wherein said metallic nitride

Attorney Docket No: JLINP055